**DOCKET NO.: 206342US2** 

"RESPONSE UNDER 37 CFR 1.116-PROCEDURE EXAMINING

## IN THE UNITED TENT & TRADEMARK OFFICE

IN RE APPLICATION OF

TOSHIFUMI NAGAIWA, ET AL.

: **EXAMINER**: 1763

SERIAL NO: 09/840,178

FILED: APRIL 24, 2001

PECENEI C 1200 El : GROUP ART UNIT: KACK

FOR: WORKTABLE DEVICE AND

> PLASMA PROCESSING APPARATUS FOR

SEMICONDUCTOR PROCESS

## **AMENDMENT AFTER FINAL**

ASSISTANT COMMISSIONER FOR PATENTS WASHINGTON, D.C. 20231

SIR:

This is an amendment responsive to the Office Action dated October 8, 2002, please amend the above-identified application as follows:

## IN THE CLAIMS

Please cancel claims 2, 7, 15, 16 and 22-24 without prejudice.

Please amend the claims as shown in the marked-up copy to read as follows:

1. (Twice Amended) A worktable device for a semiconductor process, comprising:

a worktable having a main surface for supporting a target substrate and a sub-surface disposed around said main surface;

a cooling mechanism disposed in said worktable and configured to supply cold to the main surface and the sub-surface:

a focus ring placed on the sub-surface and configured to surround the target substrate on the main surface, said focus ring consisting essentially of a conductive material;